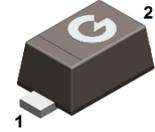


### Features

- ESD / transient protection of high speed data lines
  - IEC 61000-4-2 (ESD):  $\pm 30$  kV (air),  $\pm 30$  kV (contact)
- Low reverse stand-off voltage: 2.5V-12V
- Very low leakage current
- RoHS compliant with Halogen-free

HF



SOD-523

### Mechanical Data

- Case: SOD-523
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin-Plated Leads, Solderability-per MIL-STD-202, Method 208

### Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
ESD5Z2.5	SOD-523	3000pcs / Tape & Reel	ZD
ESD5Z3.3	SOD-523	3000pcs / Tape & Reel	ZE
ESD5Z5.0	SOD-523	3000pcs / Tape & Reel	ZF
ESD5Z6.0	SOD-523	3000pcs / Tape & Reel	ZG
ESD5Z7.0	SOD-523	3000pcs / Tape & Reel	ZH
ESD5Z12	SOD-523	3000pcs / Tape & Reel	ZM

### Maximum Ratings (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
IEC 61000-4-2; ESD (Air)	$V_{ESD-A}$	$\pm 30$	kV
IEC 61000-4-2; ESD (Contact)	$V_{ESD-C}$	$\pm 30$	kV
JESD22-A114-B; ESD (Human Body)	$V_{ESD-HB}$	$\pm 16$	kV
JESD22-A114-B; ESD (Machine)	$V_{ESD-M}$	$\pm 0.4$	kV
Total Power Dissipation	$P_D$	0.15	W

### Thermal Characteristics

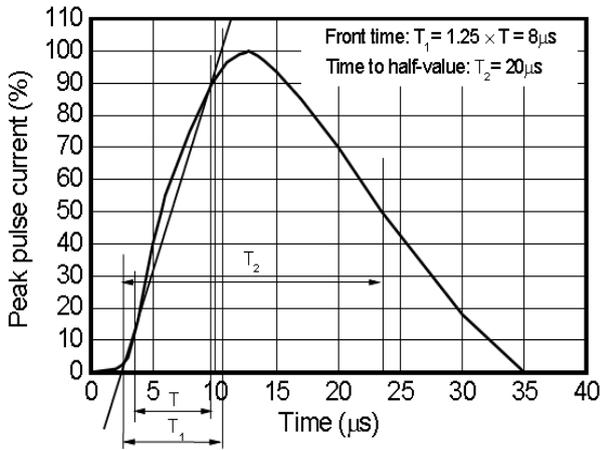
Parameter	Symbol	Value	Unit
Thermal Resistance Junction-to-Air	$R_{\theta JA}$	834	$^\circ\text{C/W}$
Thermal Resistance Junction-to-Case	$R_{\theta JC}$	542	$^\circ\text{C/W}$
Thermal Resistance Junction-to-Lead	$R_{\theta JL}$	515	$^\circ\text{C/W}$
Junction Temperature	$T_J$	-55 ~ +150	$^\circ\text{C}$
Storage Temperature Range	$T_{STG}$	-55 ~ +150	$^\circ\text{C}$

### Electrical Characteristics (@ T<sub>A</sub> = 25°C unless otherwise specified)

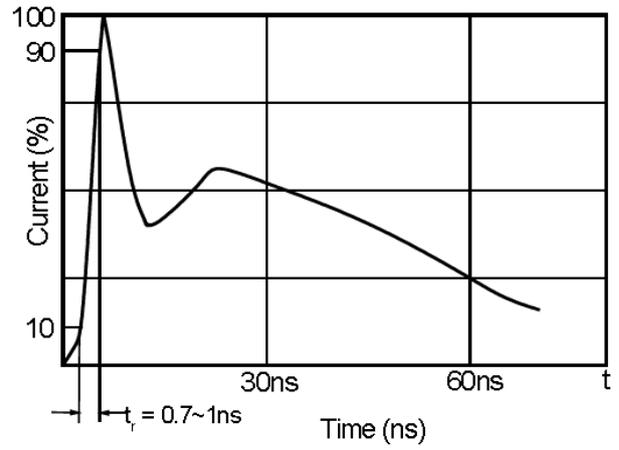
Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
<b>ESD5Z2.5 TVS for 2.5V Lines</b>						
Reverse Stand-off Voltage	V <sub>RWM</sub>		-	-	2.5	V
Peak Pulse Power (t <sub>p</sub> = 8/20μs)	P <sub>PP</sub>		-	-	120	W
Reverse Breakdown Voltage	V <sub>(BR)</sub>	I <sub>T</sub> = 1mA	4	-	-	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 2.5V	-	-	6	μA
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 5A, t <sub>p</sub> = 8/20μs	-	6.5	8	V
		I <sub>PP</sub> = 11A, t <sub>p</sub> = 8/20μs	-	-	10.9	V
Junction Capacitance	C <sub>J</sub>	V <sub>R</sub> = 0V, f = 1MHZ	-	145	-	pF
<b>ESD5Z3.3 TVS for 3.3V Lines</b>						
Reverse Stand-off Voltage	V <sub>RWM</sub>		-	-	3.3	V
Peak Pulse Power (t <sub>p</sub> = 8/20μs)	P <sub>PP</sub>		-	-	158	W
Reverse Breakdown Voltage	V <sub>(BR)</sub>	I <sub>T</sub> = 1mA	5	-	-	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 3.3V	-	-	1	μA
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 5A, t <sub>p</sub> = 8/20μs	-	8.4	10	V
		I <sub>PP</sub> = 11.2A, t <sub>p</sub> = 8/20μs	-	-	14.1	V
Junction Capacitance	C <sub>J</sub>	V <sub>R</sub> = 0V, f = 1MHZ	-	105	-	pF
<b>ESD5Z5.0 TVS for 5.0V Lines</b>						
Reverse Stand-off Voltage	V <sub>RWM</sub>		-	-	5.0	V
Peak Pulse Power (t <sub>p</sub> = 8/20μs)	P <sub>PP</sub>		-	-	174	W
Reverse Breakdown Voltage	V <sub>(BR)</sub>	I <sub>T</sub> = 1mA	6.2	-	-	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 5V	-	-	0.05	μA
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 5A, t <sub>p</sub> = 8/20μs	-	11.6	13	V
		I <sub>PP</sub> = 9.4A, t <sub>p</sub> = 8/20μs	-	-	18.6	V
Junction Capacitance	C <sub>J</sub>	V <sub>R</sub> = 0V, f = 1MHZ	-	80	-	pF
<b>ESD5Z6.0 TVS for 6.0V Lines</b>						
Reverse Stand-off Voltage	V <sub>RWM</sub>		-	-	6.0	V
Peak Pulse Power (t <sub>p</sub> = 8/20μs)	P <sub>PP</sub>		-	-	181	W
Reverse Breakdown Voltage	V <sub>(BR)</sub>	I <sub>T</sub> = 1mA	6.8	-	-	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 6V	-	-	0.01	μA
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 5A, t <sub>p</sub> = 8/20μs	-	12.4	14	V
		I <sub>PP</sub> = 8.8A, t <sub>p</sub> = 8/20μs	-	-	20.5	V
Junction Capacitance	C <sub>J</sub>	V <sub>R</sub> = 0V, f = 1MHZ	-	70	-	pF

ESD5Z7.0 TVS for 7.0V Lines						
Reverse Stand-off Voltage	$V_{RWM}$		-	-	7.0	V
Peak Pulse Power ( $t_p = 8/20\mu s$ )	$P_{PP}$		-	-	200	W
Reverse Breakdown Voltage	$V_{(BR)}$	$I_T = 1mA$	7.5	-	9	V
Reverse Leakage Current	$I_R$	$V_{RWM} = 7V$	-	-	0.01	$\mu A$
Clamping Voltage	$V_C$	$I_{PP} = 5A, t_p = 8/20\mu s$	-	13.5	16	V
		$I_{PP} = 8.8A, t_p = 8/20\mu s$	-	-	22.7	V
Junction Capacitance	$C_J$	$V_R = 0V, f = 1MHz$	-	65	-	pF
ESD5Z12 TVS for 12V Lines						
Reverse Stand-off Voltage	$V_{RWM}$		-	-	12	V
Peak Pulse Power ( $t_p = 8/20\mu s$ )	$P_{PP}$		-	-	240	W
Reverse Breakdown Voltage	$V_{(BR)}$	$I_T = 1mA$	14.1	-	-	V
Reverse Leakage Current	$I_R$	$V_{RWM} = 12V$	-	-	0.01	$\mu A$
Clamping Voltage	$V_C$	$I_{PP} = 5A, t_p = 8/20\mu s$	-	17	20	V
		$I_{PP} = 9.6A, t_p = 8/20\mu s$	-	-	25	V
Junction Capacitance	$C_J$	$V_R = 0V, f = 1MHz$	-	55	-	pF

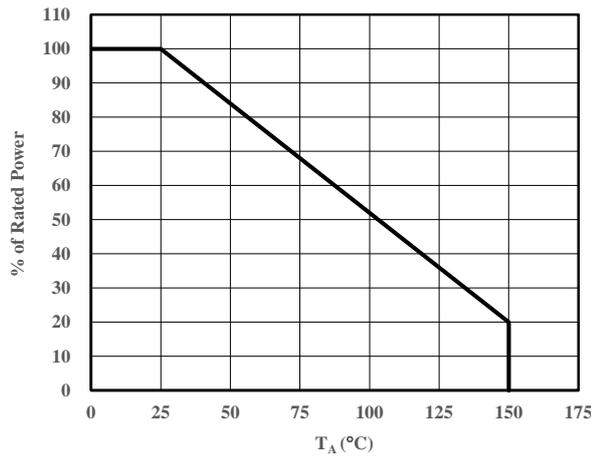
**Ratings and Characteristic Curves** (@  $T_A = 25^\circ\text{C}$  unless otherwise specified)



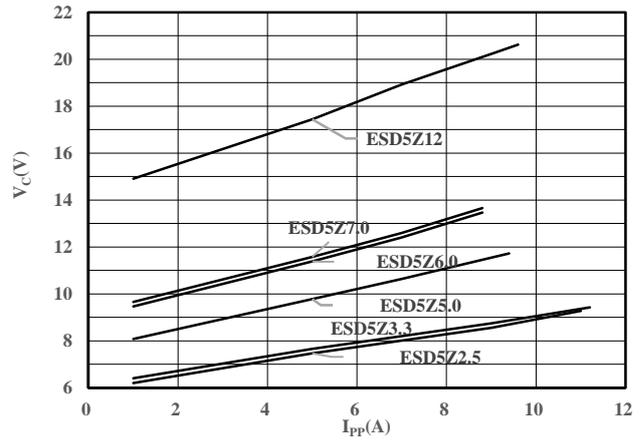
**Fig 1** 8/20  $\mu\text{s}$  waveform per IEC61000-4-5



**Fig 2** ESD pulse waveform according to IEC61000-4-2

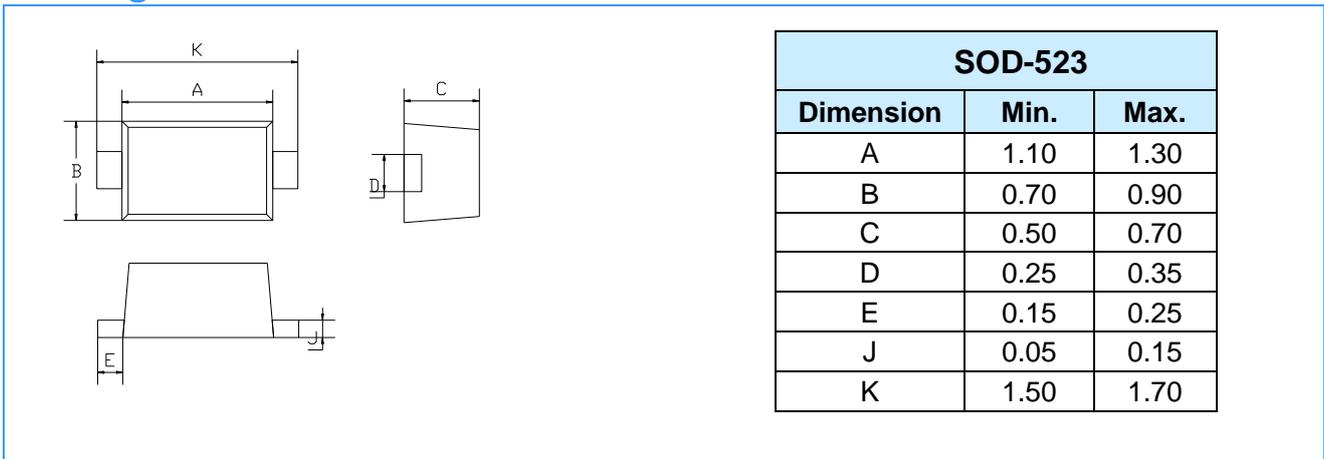


**Fig 3** Power Derating Curve



**Fig 4** Clamping Voltage vs. Peak Pulse Current

**Package Outline Dimensions** (Unit: mm)



**Package Outline Dimensions** (Unit: mm)

